

#### **Features**

- $BV_{ceo} > -60V$
- I<sub>C</sub> = -600mA Collector Current
- Ultra-Small Surface Mount Package
- Complementary NPN Type: MMDT2222V
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

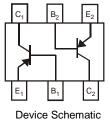
- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.003 grams (Approximate)

SOT-563

**Top View** 



Bottom View



Ordering Information (Note 4)

Part Number	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
MMDT2907V-7	Active	AEC-Q101	KAU	7	8mm	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

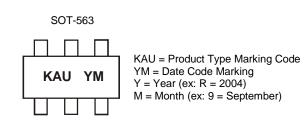
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**

Notes:



Date Code K	ley											
Year	2014	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	В	С	D	E	F	G	Н	I	J	K	L	М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current	lc	-600	mA

## **Thermal Characteristics**

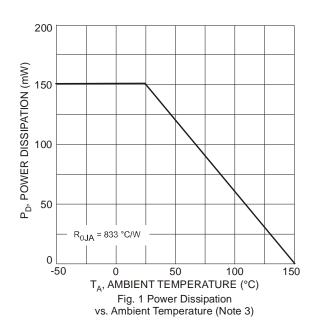
Total Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta}$ JA	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

#### ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

 For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:

# **Thermal Characteristics and Derating Information**





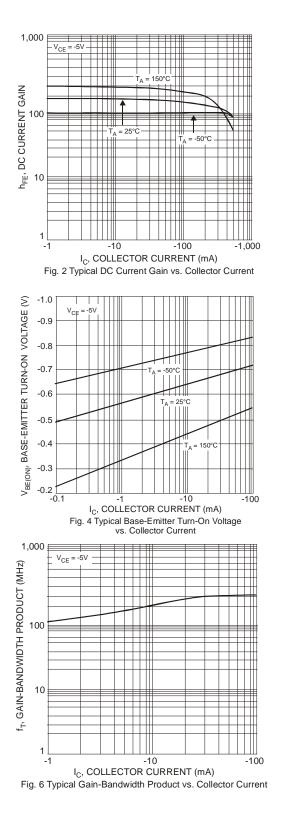
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-60	_	V	$I_{C} = -10 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-60	—	V	$I_{C} = -10 mA, I_{B} = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	_	V	$I_{E} = -10\mu A, I_{C} = 0$
Collector Cut-Off Current		_	-10	nA μA	$V_{CB} = -50V, I_E = 0$ $V_{CB} = -50V, I_E = 0, T_A = +125^{\circ}C$
Collector Cut-Off Current	ICEX		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
Base Cut-Off Current	I <sub>BL</sub>	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
ON CHARACTERISTICS					
DC Current Gain ( Note 7)	h <sub>FE</sub>	75 100 100 100 50	  300 	_	$ \begin{array}{ll} I_{C}=~-100\mu A,V_{CE}=~-10V\\ I_{C}=~-1.0mA,V_{CE}=~-10V\\ I_{C}=~-10mA,V_{CE}=~-10V\\ I_{C}=~-150mA,V_{CE}=~-10V\\ I_{C}=~-500mA,V_{CE}=~-10V\\ \end{array} $
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE</sub> (SAT)	_	-0.4 -1.6	V	$I_{C} = -150 \text{mA}, I_{B} = -15 \text{mA}$ $I_{C} = -500 \text{mA}, I_{B} = -50 \text{mA}$
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(SAT)</sub>	_	-1.3 -2.6	V	I <sub>C</sub> = -150mA, I <sub>B</sub> = -15mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
SMALL SIGNAL CHARACTERISTICS					•
Output Capacitance	Cobo	—	8.0	pF	$V_{CB} = -10V, f = 1MHz, I_E = 0$
Input Capacitance	C <sub>ibo</sub>	—	30	pF	$V_{EB} = -2V$ , f = 1MHz, I <sub>C</sub> = 0
Current Gain-Bandwidth Product	f⊤	200	—	MHz	$V_{CE} = -20V, I_C = -50mA, f = 100MHz$
SWITCHING CHARACTERISTICS					
Turn-On Time	t <sub>off</sub>	_	45	ns	$V_{CC} = -30V, I_{C} = -150mA,$
Delay Time	t <sub>d</sub>	_	10	ns	$V_{CC} = -30V, I_C = -150MA,$ $-I_{B1} = -15mA$
Rise Time	tr	_	40	ns	
Turn-Off Time	t <sub>off</sub>	—	100	ns	1/2 = -61/1 = -150mA
Storage Time	ts	_	80	ns	$-V_{CC} = -6V, I_C = -150mA,$ $-I_{B1} = I_{B2} = -15mA$
Fall Time	t <sub>f</sub>	_	30	ns	$_{1B1} = _{1B2} ={10} _{10}$

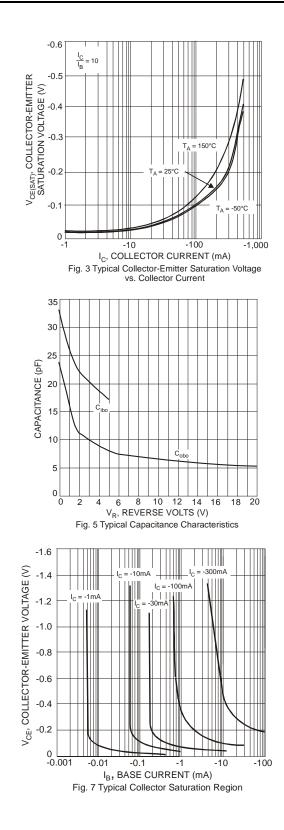
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$ 2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

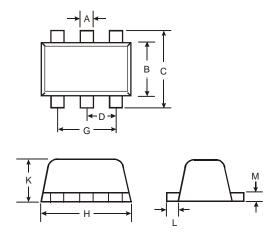






# **Package Outline Dimensions**

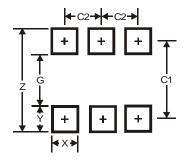
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT- 563						
Dim	Min	Max	Тур			
Α	0.15	0.30	0.20			
В	1.10	1.25	1.20			
с	1.55	1.70	1.60			
D	-	-	0.50			
G	0.90	1.10	1.00			
H	1.50	1.70	1.60			
ĸ	0.55	0.60	0.60			
1	0.10	0.30	0.20			
Μ	0.10	0.18	0.11			
All	Dimens	sions in	mm			

## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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